



# LC<sup>2</sup>MOS Precision 5 V/3 V Quad SPST Switches

## ADG511/ADG512/ADG513

### FEATURES

**+3 V, +5 V or  $\pm 5$  V Power Supplies**  
**Ultralow Power Dissipation ( $<0.5 \mu\text{W}$ )**  
**Low Leakage ( $<100 \text{ pA}$ )**  
**Low On Resistance ( $<50 \Omega$ )**  
**Fast Switching Times**  
**Low Charge Injection**  
**TTL/CMOS Compatible**  
**16-Pin DIP or SOIC Package**

### APPLICATIONS

**Battery Powered Instruments**  
**Single Supply Systems**  
**Remote Powered Equipment**  
**+5 V Supply Systems**  
**Computer Peripherals such as Disk Drives**  
**Precision Instrumentation**  
**Audio and Video Switching**  
**Automatic Test Equipment**  
**Precision Data Acquisition**  
**Sample Hold Systems**  
**Communication Systems**  
**Compatible with  $\pm 5$  V Supply DACs and ADCs such as AD7840/8, AD7870/1/2/4/5/6/8**

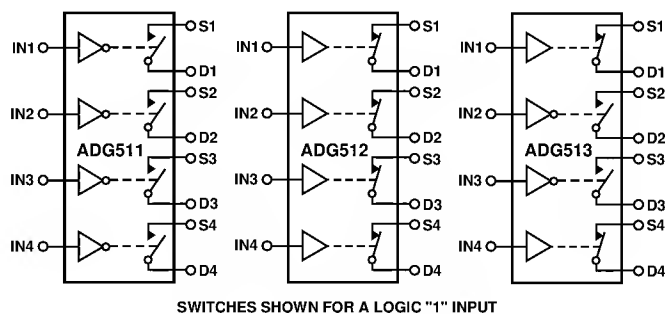
### GENERAL DESCRIPTION

The ADG511, ADG512 and ADG513 are monolithic CMOS ICs containing four independently selectable analog switches. These switches feature low, well-controlled on resistance and wide analog signal range, making them ideal for precision analog signal switching.

These switch arrays are fabricated using Analog Devices' advanced linear compatible CMOS (LC<sup>2</sup>MOS) process which offers the additional benefits of low leakage currents, ultralow power dissipation and low capacitance for fast switching speeds with minimum charge injection. These features make the ADG511, ADG512 and ADG513 the optimum choice for a wide variety of signal switching tasks in precision analog signal processing and data acquisition systems.

The ability to operate from single +3 V, +5 V or  $\pm 5$  V bipolar supplies make the ADG511, ADG512 and ADG513 perfect for use in battery-operated instruments, 4–20 mA loop systems and with the new generation of DACs and ADCs from Analog Devices. The use of 5 V supplies and reduced operating currents give much lower power dissipation than devices operating from  $\pm 15$  V supplies.

### FUNCTIONAL BLOCK DIAGRAM



The ADG511, ADG512 and ADG513 contain four independent SPST switches. The ADG511 and ADG512 differ only in that the digital control logic is inverted. The ADG511 switch is turned on with a logic low on the appropriate control input, while a logic high is required for the ADG512. The ADG513 contains two switches whose digital control logic is similar to that of the ADG511 while the logic is inverted in the remaining two switches.

### PRODUCT HIGHLIGHTS

- +5 Volt Single Supply Operation**  
The ADG511/ADG512/ADG513 offers high performance, including low on resistance and wide signal range, fully specified and guaranteed with +3 V,  $\pm 5$  V as well as +5 V supply rails.
- Ultralow Power Dissipation**  
CMOS construction ensures ultralow power dissipation.
- Low  $R_{ON}$**
- Break-Before-Make Switching**  
Switches are guaranteed to have break-before-make operation. This allows multiple outputs to be tied together for multiplexer applications without the possibility of momentary shorting between channels.

### REV. A

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# ADG511/ADG512/ADG513- SPECIFICATIONS<sup>1</sup>

**Dual Supply** ( $V_{DD} = +5\text{ V} \pm 10\%$ ,  $V_{SS} = -5\text{ V} \pm 10\%$ ,  $GND = 0\text{ V}$ , unless otherwise noted)

Parameter	B Versions		T Versions		Units	Test Conditions/Comments
	+25°C	-40°C to +85°C	+25°C	-55°C to +125°C		
ANALOG SWITCH Analog Signal Range $R_{ON}$	30	$V_{DD}$ to $V_{SS}$ 50	30	$V_{DD}$ to $V_{SS}$ 50	V $\Omega$ typ $\Omega$ max	$V_D = \pm 3.5\text{ V}$ , $I_S = -10\text{ mA}$ ; $V_{DD} = +4.5\text{ V}$ , $V_{SS} = -4.5\text{ V}$
LEAKAGE CURRENTS Source OFF Leakage $I_S$ (OFF)	$\pm 0.025$ $\pm 0.1$	$\pm 2.5$	$\pm 0.025$ $\pm 0.1$	$\pm 2.5$	nA typ nA max	$V_{DD} = +5.5\text{ V}$ , $V_{SS} = -5.5\text{ V}$ $V_D = \pm 4.5\text{ V}$ , $V_S = \mp 4.5\text{ V}$ ; Test Circuit 2
Drain OFF Leakage $I_D$ (OFF)	$\pm 0.025$ $\pm 0.1$	$\pm 2.5$	$\pm 0.025$ $\pm 0.1$	$\pm 2.5$	nA typ nA max	$V_D = \pm 4.5\text{ V}$ , $V_S = \mp 4.5\text{ V}$ ; Test Circuit 2
Channel ON Leakage $I_D$ , $I_S$ (ON)	$\pm 0.05$ $\pm 0.2$	$\pm 2.5$ $\pm 5$	$\pm 0.05$ $\pm 0.2$	$\pm 2.5$ $\pm 5$	nA typ nA max	$V_D = V_S = \pm 4.5\text{ V}$ ; Test Circuit 3
DIGITAL INPUTS Input High Voltage, $V_{INH}$ Input Low Voltage, $V_{INL}$ Input Current $I_{INL}$ or $I_{INH}$		2.4 0.8		2.4 0.8	V min V max  $\mu\text{A}$ typ $\mu\text{A}$ max	   $V_{IN} = V_{INL}$ or $V_{INH}$
DYNAMIC CHARACTERISTICS <sup>2</sup> $t_{ON}$	200	375	200	375	ns typ ns max	$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ ; $V_S = \pm 3\text{ V}$ ; Test Circuit 4
$t_{OFF}$	120	150	120	150	ns typ ns max	$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ ; $V_S = \pm 3\text{ V}$ ; Test Circuit 4
Break-Before-Make Time Delay, $t_D$ (ADG513 Only)	100		100		ns typ	$R_L = 300\ \Omega$ , $C_L = 35\text{ pF}$ ; $V_{S1} = V_{S2} = +3\text{ V}$ ; Test Circuit 5
Charge Injection	11		11		pC typ	$V_S = 0\text{ V}$ , $R_S = 0\ \Omega$ , $C_L = 10\text{ nF}$ ; Test Circuit 6
OFF Isolation	68		68		dB typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; Test Circuit 7
Channel-to-Channel Crosstalk	85		85		dB typ	$R_L = 50\ \Omega$ , $C_L = 5\text{ pF}$ , $f = 1\text{ MHz}$ ; Test Circuit 8
$C_S$ (OFF)	9		9		pF typ	$f = 1\text{ MHz}$
$C_D$ (OFF)	9		9		pF typ	$f = 1\text{ MHz}$
$C_D$ , $C_S$ (ON)	35		35		pF typ	$f = 1\text{ MHz}$
POWER REQUIREMENTS $V_{DD}$ $V_{SS}$ $I_{DD}$		+4.5/5.5 -4.5/-5.5		+4.5/5.5 -4.5/-5.5	V min/max V min/max $\mu\text{A}$ typ	$V_{DD} = +5.5\text{ V}$ , $V_{SS} = -5.5\text{ V}$ Digital Inputs = 0 V or 5 V
	0.0001	1	0.0001	1	$\mu\text{A}$ max	
$I_{SS}$	0.0001	1	0.0001	1	$\mu\text{A}$ typ $\mu\text{A}$ max	

## NOTES

<sup>1</sup>Temperature ranges are as follows: B Versions -40°C to +85°C; T Versions -55°C to +125°C.

<sup>2</sup>Guaranteed by design, not subject to production test.

Specifications subject to change without notice.

**Single Supply** ( $V_{DD} = +5\text{ V} \pm 10\%$ ,  $V_{SS} = 0\text{ V}$ ,  $GND = 0\text{ V}$ , unless otherwise noted)

Parameter	B Versions		T Versions		Units	Test Conditions/Comments
	+25°C	-40°C to +85°C	+25°C	-55°C to +125°C		
ANALOG SWITCH Analog Signal Range R <sub>ON</sub>	45	0 V to V <sub>DD</sub> 75	45	0 V to V <sub>DD</sub> 75	V Ω typ Ω max	V <sub>D</sub> = +3.5 V, I <sub>S</sub> = -10 mA; V <sub>DD</sub> = +4.5 V
LEAKAGE CURRENTS Source OFF Leakage I <sub>S</sub> (OFF)  Drain OFF Leakage I <sub>D</sub> (OFF)  Channel ON Leakage I <sub>D</sub> , I <sub>S</sub> (ON)	±0.025 ±0.1 ±0.025 ±0.1 ±0.05 ±0.2	±2.5 ±2.5 ±5	±0.025 ±0.1 ±0.025 ±0.1 ±0.05 ±0.2	±2.5 ±2.5 ±5	nA typ nA max nA typ nA max nA typ nA max	V <sub>DD</sub> = +5.5 V V <sub>D</sub> = 4.5/1 V, V <sub>S</sub> = 1/4.5 V; Test Circuit 2 V <sub>D</sub> = 4.5/1 V, V <sub>S</sub> = 1/4.5 V; Test Circuit 2 V <sub>D</sub> = V <sub>S</sub> = +4.5 V/+1 V; Test Circuit 3
DIGITAL INPUTS Input High Voltage, V <sub>INH</sub> Input Low Voltage, V <sub>INL</sub> Input Current I <sub>INL</sub> or I <sub>INH</sub>		2.4 0.8 0.005 ±0.1		2.4 0.8 0.005 ±0.1	V min V max μA typ μA max	V <sub>IN</sub> = V <sub>INL</sub> or V <sub>INH</sub>
DYNAMIC CHARACTERISTICS <sup>2</sup> t <sub>ON</sub>  t <sub>OFF</sub>  Break-Before-Make Time Delay, t <sub>D</sub> (ADG513 Only) Charge Injection  OFF Isolation  Channel-to-Channel Crosstalk  C <sub>S</sub> (OFF) C <sub>D</sub> (OFF) C <sub>D</sub> , C <sub>S</sub> (ON)	250 50 200 16 68 85 9 9 35	500 100	250 50 200 16 68 85 9 9 35	500 100	ns typ ns max ns typ ns max ns typ pC typ dB typ dB typ pF typ pF typ pF typ	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF; V <sub>S</sub> = +2 V; Test Circuit 4 R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF; V <sub>S</sub> = +2 V; Test Circuit 4 R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF; V <sub>S1</sub> = V <sub>S2</sub> = +2 V; Test Circuit 5 V <sub>S</sub> = 0 V, R <sub>S</sub> = 0 Ω, C <sub>L</sub> = 10 nF; Test Circuit 6 R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; Test Circuit 7 R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz; Test Circuit 8 f = 1 MHz f = 1 MHz f = 1 MHz
POWER REQUIREMENTS V <sub>DD</sub> I <sub>DD</sub>	0.0001 1	+4.5/5.5	0.0001 1	+4.5/5.5	V min/max μA typ μA max	V <sub>DD</sub> = +5.5 V Digital Inputs = 0 V or 5 V

## NOTES

<sup>1</sup>Temperature ranges are as follows: B Versions -40°C to +85°C; T Versions -55°C to +125°C.

<sup>2</sup>Guaranteed by design, not subject to production test.

Specifications subject to change without notice.

# ADG511/ADG512/ADG513- SPECIFICATIONS<sup>1</sup>

## Single Supply ( $V_{DD} = +3.3 \text{ V} \pm 10\%$ , $V_{SS} = 0 \text{ V}$ , $GND = 0 \text{ V}$ , unless otherwise noted)

Parameter	B Versions		Units	Test Conditions/Comments
	+25°C	0°C to +70°C		
ANALOG SWITCH Analog Signal Range $R_{ON}$	200	0 V to $V_{DD}$ 500	V $\Omega$ typ $\Omega$ max	$V_D = +1.5 \text{ V}$ , $I_S = -1 \text{ mA}$ ; $V_{DD} = +3 \text{ V}$ ,
LEAKAGE CURRENTS Source OFF Leakage $I_S$ (OFF) Drain OFF Leakage $I_D$ (OFF) Channel ON Leakage $I_D$ , $I_S$ (ON)	$\pm 0.025$ $\pm 0.1$ $\pm 0.025$ $\pm 0.1$ $\pm 0.05$ $\pm 0.2$	$\pm 2.5$ $\pm 2.5$ $\pm 2.5$ $\pm 5$	nA typ nA max nA typ nA max nA typ nA max	$V_{DD} = +3.6 \text{ V}$ $V_D = 2.6/1 \text{ V}$ , $V_S = 1/2.6 \text{ V}$ ; Test Circuit 2 $V_D = 2.6/1 \text{ V}$ , $V_S = 1/2.6 \text{ V}$ ; Test Circuit 2 $V_D = V_S = +2.6 \text{ V}/+1 \text{ V}$ ; Test Circuit 3
DIGITAL INPUTS Input High Voltage, $V_{INH}$ Input Low Voltage, $V_{INL}$ Input Current $I_{INL}$ or $I_{INH}$		2.4 0.8 $\pm 0.1$	V min V max $\mu\text{A}$ typ $\mu\text{A}$ max	$V_{IN} = V_{INL}$ or $V_{INH}$
DYNAMIC CHARACTERISTICS <sup>2</sup> $t_{ON}$ $t_{OFF}$ Break-Before-Make Time Delay, $t_D$ (ADG513 Only) Charge Injection OFF Isolation Channel-to-Channel Crosstalk $C_S$ (OFF) $C_D$ (OFF) $C_D$ , $C_S$ (ON)	600 100 500 11 68 85 9 9 35	1200 160	ns typ ns max ns typ ns max ns typ pC typ dB typ dB typ pF typ pF typ pF typ	$R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$ ; $V_S = +1 \text{ V}$ ; Test Circuit 4 $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$ ; $V_S = +1 \text{ V}$ ; Test Circuit 4 $R_L = 300 \Omega$ , $C_L = 35 \text{ pF}$ ; $V_{S1} = V_{S2} = +1 \text{ V}$ ; Test Circuit 5 $V_S = 0 \text{ V}$ , $R_S = 0 \Omega$ , $C_L = 10 \text{ nF}$ ; Test Circuit 6 $R_L = 50 \Omega$ , $C_L = 5 \text{ pF}$ , $f = 1 \text{ MHz}$ ; Test Circuit 7 $R_L = 50 \Omega$ , $C_L = 5 \text{ pF}$ , $f = 1 \text{ MHz}$ ; Test Circuit 8 $f = 1 \text{ MHz}$ $f = 1 \text{ MHz}$ $f = 1 \text{ MHz}$
POWER REQUIREMENTS $V_{DD}$ $I_{DD}$	0.0001	3/3.6 1	V min/max $\mu\text{A}$ typ $\mu\text{A}$ max	$V_{DD} = +3.6 \text{ V}$ Digital Inputs = 0 V or 3 V

### NOTES

<sup>1</sup>Temperature ranges are as follows: B Versions -40°C to +70°C.

<sup>2</sup>Guaranteed by design, not subject to production test.

Specifications subject to change without notice.

# ADG511/ADG512/ADG513

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

(T<sub>A</sub> = +25°C unless otherwise noted)

V <sub>DD</sub> to V <sub>SS</sub>	+44 V
V <sub>DD</sub> to GND	-0.3 V to +25 V
V <sub>SS</sub> to GND	+0.3 V to -25 V
Analog, Digital Inputs <sup>2</sup>	V <sub>SS</sub> -2 V to V <sub>DD</sub> + 2 V or 30 mA, Whichever Occurs First
Continuous Current, S or D	30 mA
Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle max)	100 mA
Operating Temperature Range	
Industrial (B Version)	-40°C to +85°C
Extended (T Version)	-55°C to +125°C
Storage Temperature Range	-65°C to +150°C
Junction Temperature	+150°C
Cerdip Package, Power Dissipation	900 mW
θ <sub>JA</sub> Thermal Impedance	76°C/W
Lead Temperature, Soldering (10 sec)	+300°C

Plastic Package, Power Dissipation	470 mW
θ <sub>JA</sub> Thermal Impedance	117°C/W
Lead Temperature, Soldering (10 sec)	+260°C
SOIC Package, Power Dissipation	600 mW
θ <sub>JA</sub> Thermal Impedance	77°C/W
Lead Temperature, Soldering	
Vapor Phase (60 sec)	+215°C
Infrared (15 sec)	+220°C

## NOTES

<sup>1</sup>Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

<sup>2</sup>Overt voltages at I<sub>N</sub>, S or D will be clamped by internal diodes. Current should be limited to the maximum ratings given.

## CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although the ADG511/ADG512/ADG513 features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



## ORDERING GUIDE

Model <sup>1</sup>	Temperature Range <sup>2</sup>	Package Option <sup>3</sup>
ADG511BN	-40°C to +85°C	N-16
ADG511BR	-40°C to +85°C	R-16A
ADG511TQ	-55°C to +125°C	Q-16
ADG512BN	-40°C to +85°C	N-16
ADG512BR	-40°C to +85°C	R-16A
ADG512TQ	-55°C to +125°C	Q-16
ADG513BN	-40°C to +85°C	N-16
ADG513BR	-40°C to +85°C	R-16A

## NOTES

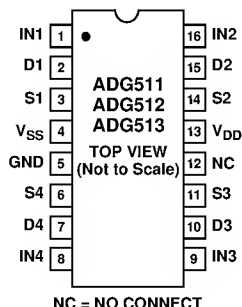
<sup>1</sup>To order MIL-STD-883, Class B processed parts, add /883B to T grade part numbers.

<sup>2</sup>3.3 V specifications apply over 0°C to +70°C temperature range.

<sup>3</sup>N = Plastic DIP; R = 0.15" Small Outline IC (SOIC); Q = Cerdip.

# ADG511/ADG512/ADG513

## PIN CONFIGURATION (DIP/SOIC)



Truth Table (ADG511/ADG512)

ADG511 In	ADG512 In	Switch Condition
0	1	ON
1	0	OFF

Truth Table (ADG513)

Logic	Switch 1, 4	Switch 2, 3
0	OFF	ON
1	ON	OFF

## TERMINOLOGY

$V_{DD}$	Most positive power supply potential.
$V_{SS}$	Most negative power supply potential in dual supplies. In single supply applications, it may be connected to GND.
GND	Ground (0 V) reference.
S	Source terminal. May be an input or output.
D	Drain terminal. May be an input or output.
IN	Logic control input.
$R_{ON}$	Ohmic resistance between D and S.
$I_S$ (OFF)	Source leakage current with the switch "OFF."
$I_D$ (OFF)	Drain leakage current with the switch "OFF."
$I_D, I_S$ (ON)	Channel leakage current with the switch "ON."
$V_D$ ( $V_S$ )	Analog voltage on terminals D, S.
$C_S$ (OFF)	"OFF" switch source capacitance.
$C_D$ (OFF)	"OFF" switch drain capacitance.
$C_D, C_S$ (ON)	"ON" switch capacitance.
$t_{ON}$	Delay between applying the digital control input and the output switching on.
$t_{OFF}$	Delay between applying the digital control input and the output switching off.
$t_D$	"OFF" or "ON" time measured between the 90% points of both switches when switching from one address state to another.
Crosstalk	A measure of unwanted signal which is coupled through from one channel to another as a result of parasitic capacitance.
Off Isolation	A measure of unwanted signal coupling through an "OFF" switch.
Charge Injection	A measure of the glitch impulse transferred from the digital input to the analog output during switching.

# Typical Performance Graphs- ADG511/ADG512/ADG513

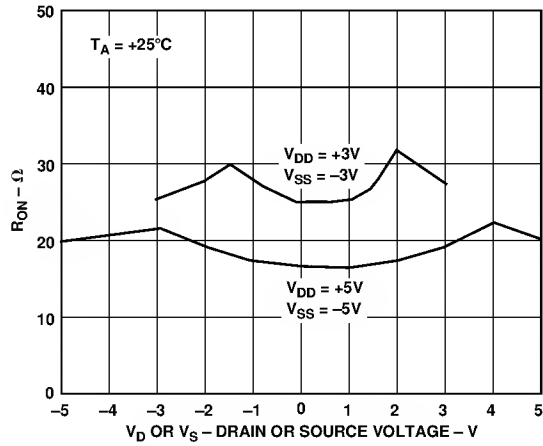


Figure 1. On Resistance as a Function of  $V_D$  ( $V_S$ ) Dual Supplies

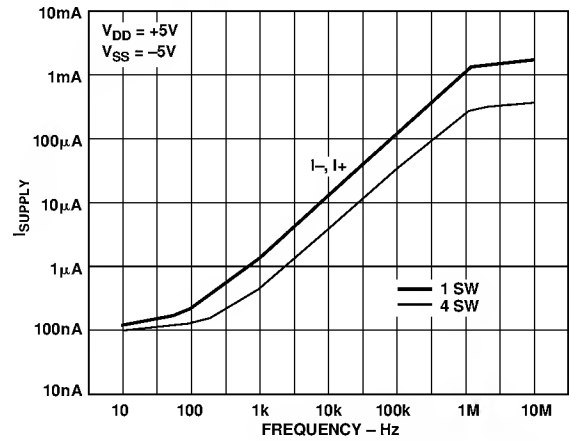


Figure 4. Supply Current vs. Input Switching Frequency

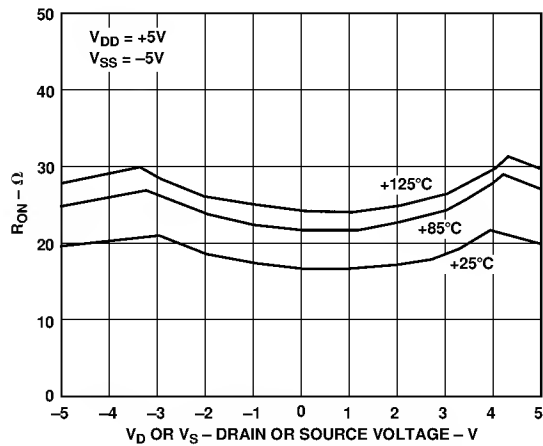


Figure 2. On Resistance as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures

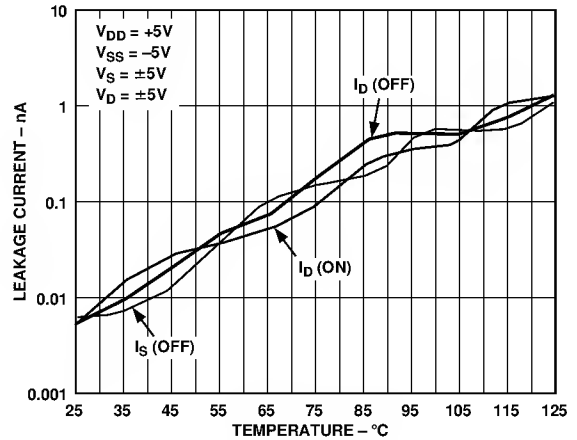


Figure 5. Leakage Currents as a Function of Temperature

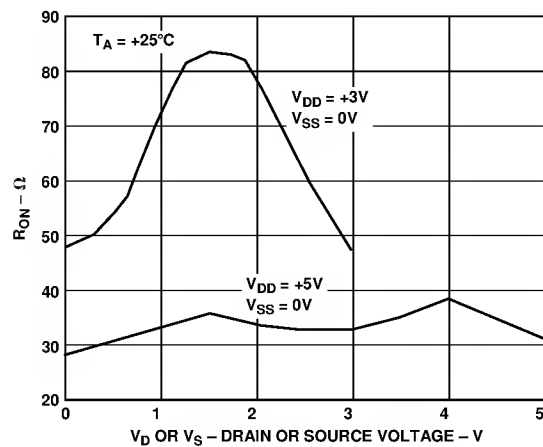


Figure 3. On Resistance as a Function of  $V_D$  ( $V_S$ ) Single Supply

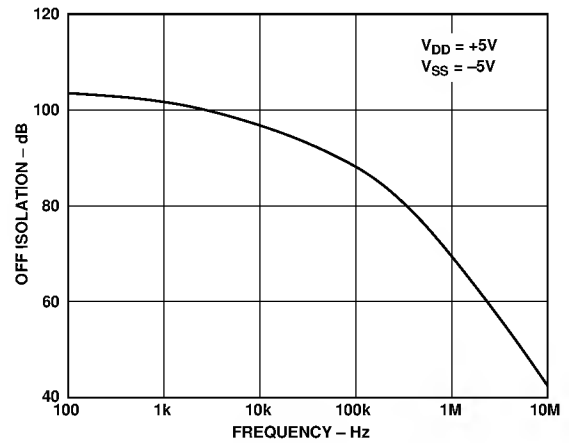


Figure 6. Off Isolation vs. Frequency

# ADG511/ADG512/ADG513

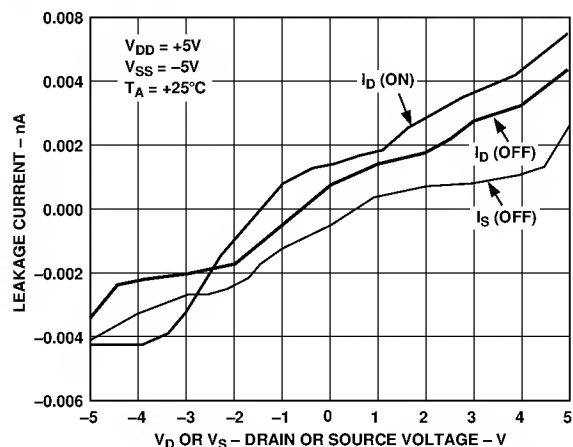


Figure 7. Leakage Currents as a Function of  $V_D$  ( $V_S$ )

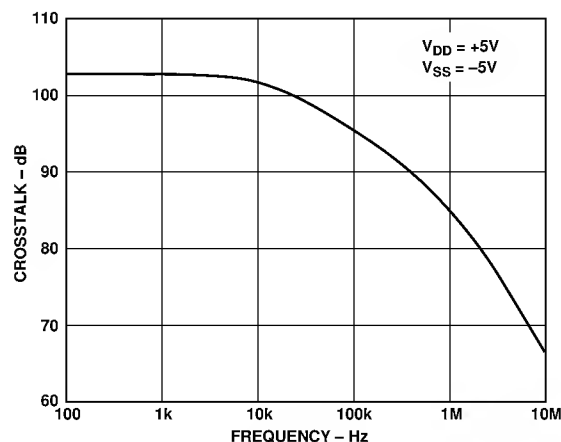


Figure 8. Crosstalk vs. Frequency

## APPLICATION

Figure 9 illustrates a precise sample-and-hold circuit. An AD845 is used as the input buffer while the output operational amplifier is an OP07. During the track mode, SW1 is closed and the output  $V_{OUT}$  follows the input signal  $V_{IN}$ . In the hold mode, SW1 is opened and the signal is held by the hold capacitor  $C_H$ .

Due to switch and capacitor leakage, the voltage on the hold capacitor will decrease with time. The ADG511/ADG512/ADG513 minimizes this droop due to its low leakage specifications. The droop rate is further minimized by the use of a polystyrene hold capacitor. The droop rate for the circuit shown is typically  $15 \mu V/\mu s$ .

A second switch, SW2, which operates in parallel with SW1, is included in this circuit to reduce pedestal error. Since both switches will be at the same potential, they will have a differential effect on the op amp OP07, which will minimize charge injection effects. Pedestal error is also reduced by the compensation network  $R_C$  and  $C_C$ . This compensation network also reduces the hold time glitch while optimizing the acquisition time. Using the illustrated op amps and component values, the pedestal error has a maximum value of 5 mV over the  $\pm 3 V$  input range. The acquisition time is  $2.5 \mu s$  while the settling time is  $1.85 \mu s$ .

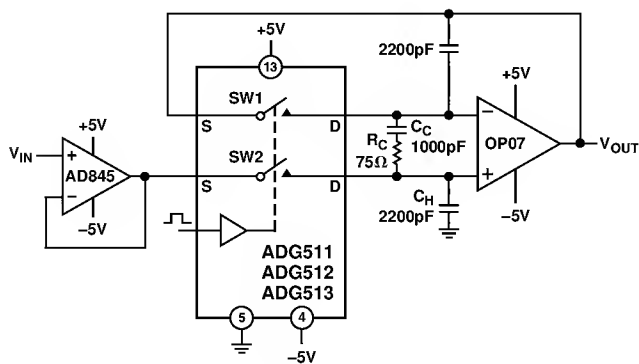
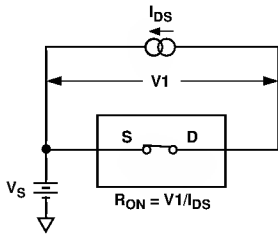


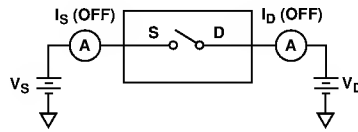
Figure 9. Accurate Sample-and-Hold



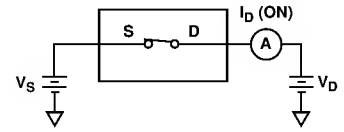
## Test Circuits



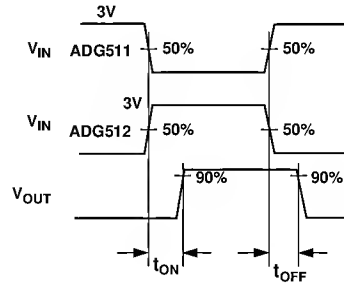
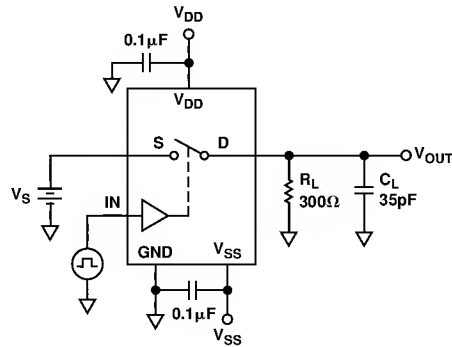
1. On Resistance



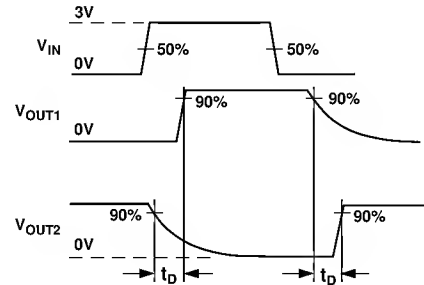
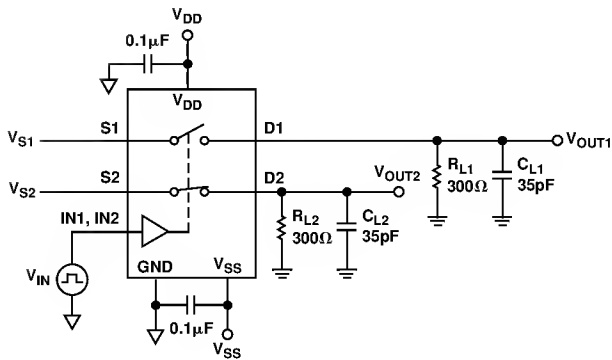
2. Off Leakage



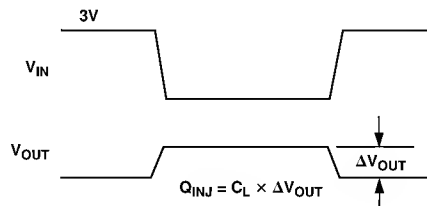
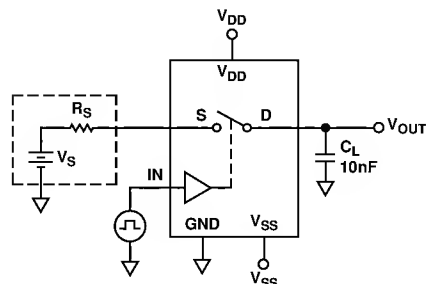
3. On Leakage



4. Switching Times



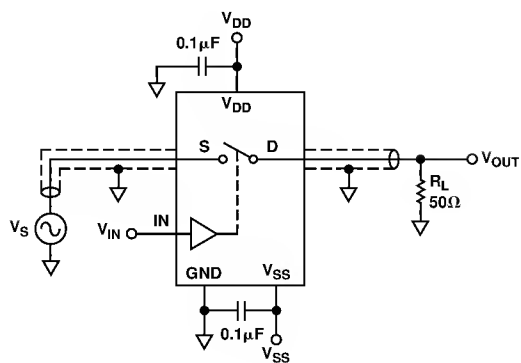
5. Break-Before-Make Time Delay



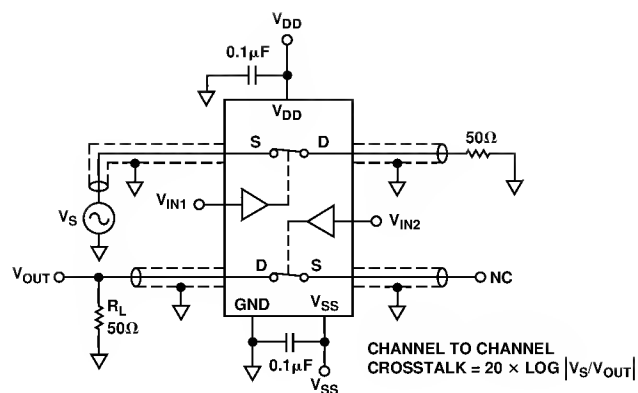
6. Charge Injection

# ADG511/ADG512/ADG513

## Test Circuits (continued)



7. Off Isolation



8. Channel-to-Channel Crosstalk

**(N-16)**

-11-

The drawing shows the 16-pin connector from three perspectives: top, side, and a detail view of the pin and housing interface.

**Top View Dimensions:**

- Overall width: 0.840 (21.34)
- Width between mounting holes: 0.745 (18.92)
- Pin 1 indicator: A circle with the number 1.
- Mounting hole diameter: 0.160 (4.06)
- Mounting hole pitch: 0.115 (2.93)
- Pin pitch: 0.022 (0.558)
- Pin width: 0.100 (2.54)
- Pin length (from seating plane): 0.070 (1.77)
- Pin length (from BSC): 0.045 (1.15)

**Side View Dimensions:**

- Overall height: 0.280 (7.11)
- Height from mounting surface to seating plane: 0.240 (6.10)
- Pin length (from seating plane): 0.130 (3.30)
- Pin length (from MIN): 0.015 (0.38)

**Detail View Dimensions:**

- Pin width: 0.325 (8.26)
- Pin length: 0.195 (4.95)
- Pin length (from MIN): 0.115 (2.93)
- Pin length (from MIN): 0.015 (0.381)
- Pin length (from MIN): 0.008 (0.204)

**Labels:**

- PIN 1
- SEATING PLANE
- BSC (Basic Stock)
- MAX (Maximum)
- MIN (Minimum)

The drawing includes the following dimensions:

- Top View:**
  - Overall width: 0.005 (0.13) MIN
  - Overall length: 0.080 (2.03) MAX
  - Pin 16 to Pin 9 distance: 0.310 (7.87)
  - Pin 9 to Pin 8 distance: 0.220 (5.59)
  - Pin 16 to Pin 1 distance: 0.160 (4.06)
  - Pin 9 to Pin 8 distance: 0.090 (2.29)
- Side View:**
  - Overall height: 0.200 (5.08) MAX
  - Pin 16 to Pin 9 distance: 0.200 (5.08)
  - Pin 9 to Pin 8 distance: 0.125 (3.18)
  - Pin 16 to Pin 9 distance: 0.023 (0.58)
  - Pin 9 to Pin 8 distance: 0.100 (2.54) BSC
  - Pin 16 to Pin 9 distance: 0.014 (0.36)
  - Pin 9 to Pin 8 distance: 0.070 (1.78)
  - Pin 16 to Pin 9 distance: 0.030 (0.76)
  - Pin 9 to Pin 8 distance: 0.060 (1.52)
  - Pin 9 to Pin 8 distance: 0.015 (0.38)
  - Pin 16 to Pin 9 distance: 0.150 (3.81) MIN
- Detail View:**
  - Overall width: 0.320 (8.13)
  - Pin 16 to Pin 9 distance: 0.290 (7.37)
  - Pin 9 to Pin 8 distance: 0.015 (0.38)
  - Pin 16 to Pin 9 distance: 0.008 (0.20)
  - Pin 9 to Pin 8 distance: 15° / 0°

Figure 1: Mechanical drawing of the 16-pin connector. The drawing shows three views: a top view, a side view, and a detail view of the connector housing. Dimensions are given in inches and millimeters. Key dimensions include: overall width 0.3937 (10.00), pin pitch 0.0192 (0.49), pin diameter 0.0098 (0.25), and housing thickness 0.0040 (0.10). The detail view shows a 45-degree angled pin with a diameter of 0.0196 (0.50) and a base diameter of 0.0099 (0.25).

